



SANYO Semiconductors

DATA SHEET

LA1266 — Monolithic Linear IC Electronic Tuning Type AM/FM Tuner System

Features

- Minimum number of external parts required.
- Excellent S/N
- Local OSC with ALC
- Local OSC buffer
- Tuning indicator pin (common with narrow-band stop signal and muting drive output)
- Variable stop sensitivity (variable separately for FM, AM)
- Less tweet interference
- Signal meter pin
- IF count output

Functions

FM : IF amplifier, quadrature detector, AF preamplifier, signal meter, IF count output, tuning indicator drive output (common with stop signal, muting drive output)

AM : RF amplifier, MIX, OSC (with ALC), IF amplifier, detector, AGC, signal meter, tuning indicator drive output (common with stop signal), IF count output, local OSC buffer.

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SANYO Semiconductor Co., Ltd.

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Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	$V_{CC\text{ max}}$	Pins 7,8,20	16	V
Flow-in current	I_g	Pin 8	20	mA
Flow-out current	I_{22}	Pin 22	1	mA
	I_{24}	Pin 24	2	mA
Allowable power dissipation	$P_d\text{ max}$	$T_a \leq 60^\circ\text{C}$	700	mW
Operating temperature	T_{opr}		-20 to +70	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +125	$^\circ\text{C}$

Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V_{CC}		8.5	V
Operating voltage range	$V_{CC\text{ op}}$		6 to 14	V

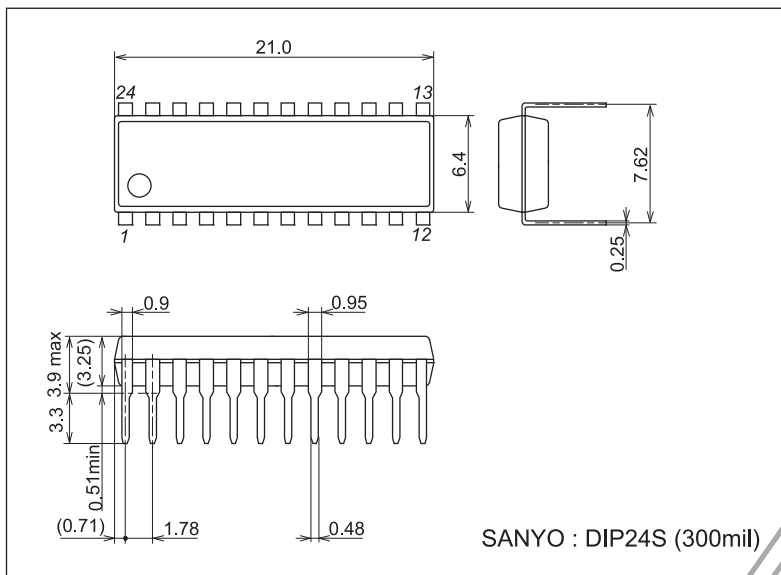
Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 8.5\text{V}$, See Test Circuit.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
AM : $f_c = 1\text{MHz}$, $f_m = 1\text{kHz}$						
Quiescent current	I_{CCO}	No input		22	30	mA
Detection output	V_{O1}	$V_{\text{IN}} = 20\text{dB}\mu$, 30% mod.	30	60	110	mV
	V_{O2}	$V_{\text{IN}} = 80\text{dB}\mu$, 30% mod.	90	150	210	mV
Signal to noise ratio	S/N1	$V_{\text{IN}} = 20\text{dB}\mu$	15	19		dB
	S/N2	$V_{\text{IN}} = 80\text{dB}\mu$	49	54		dB
Total harmonic distortion	THD1	$V_{\text{IN}} = 80\text{dB}\mu$, 30% mod.		0.3	1.0	%
	THD2	$V_{\text{IN}} = 107\text{dB}\mu$, 30% mod.		0.3	1.0	%
Signal meter output	V_{SM1}	No input	0	0	0.2	V
	V_{SM2}	$V_{\text{IN}} = 80\text{dB}\mu$	1.8	2.8	3.5	V
LED drive sensitivity	LED-ON	$I_{\text{LED}} = 1\text{mA}$	13	23	33	dBm
Local OSC buffer output	V_{OSC}	$f_{\text{osc}} = 1.45\text{MHz}$	220	280	340	mV
IF buffer output	V_{IF}	$V_{\text{IN}} = 20\text{dB}\mu$	120	180	250	mV
FM : $f_c = 10.7\text{MHz}$, $f_m = 1\text{kHz}$						
Quiescent current	I_{CCO}	No Input		29	40	mA
Input limiting sensitivity	-3dBLS	3dB down, 100% mod.		31	37	dB μ
Demodulation output	V_{O}	$V_{\text{IN}} = 100\text{dB}\mu$, 100% mod.	270	390	540	mV
S/N ratio	S/N	$V_{\text{IN}} = 100\text{dB}\mu$	78	84		dB
Total harmonic distortion	THD	$V_{\text{IN}} = 100\text{dB}\mu$, 100% mod.		0.03	0.3	%
Signal meter output	V_{SM1}	No input	0	0	0.2	V
	V_{SM2}	$V_{\text{IN}} = 100\text{dB}\mu$	1.7	2.3	3.1	V
LED drive sensitivity	LED-ON	$I_{\text{LED}} = 1\text{mA}$	46	61	76	dB μ
LED drive bandwidth	LED-BW	$V_{\text{IN}} = 100\text{dB}\mu$, $I_{\text{LED}} = 1\text{mA}$	70	105	140	kHz
AM rejection ratio	AMR	$V_{\text{IN}} = 100\text{dB}\mu$, 100% mod. AM-1kHz, 30% mod.	45	58		dB
IF buffer output	V_{IF}	$V_{\text{IN}} = 50\text{dB}\mu$	110	160	230	mV

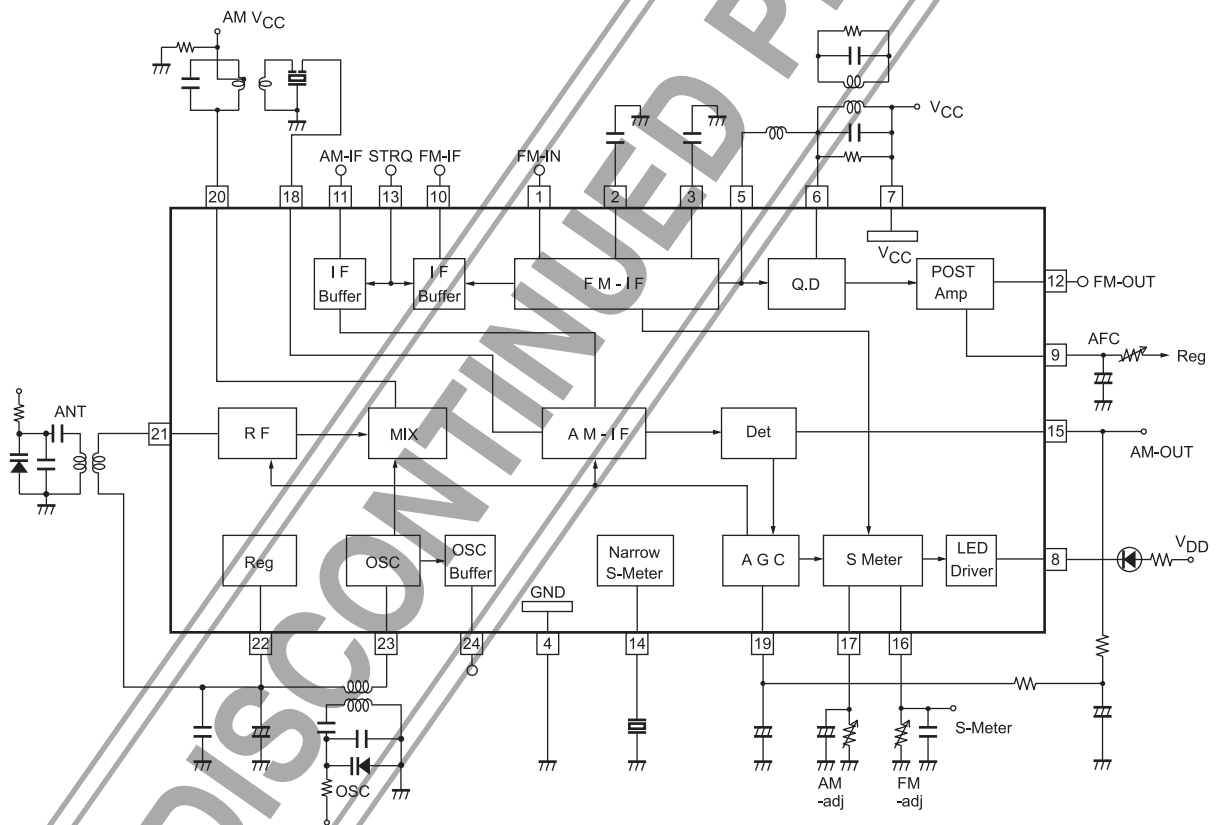
Package Dimensions

unit : mm (typ)

3067B



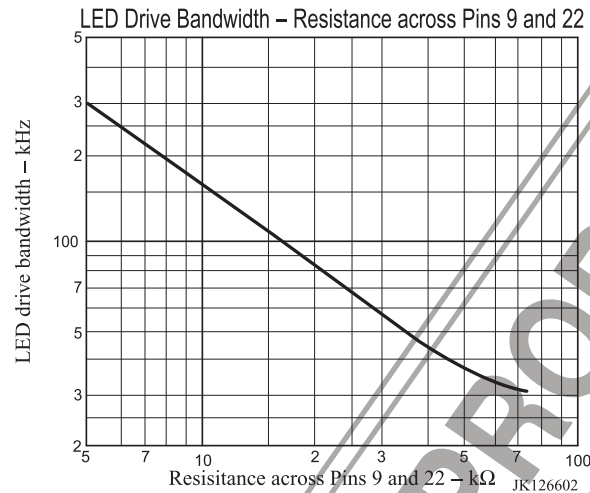
Block Diagram



How to use LA1266

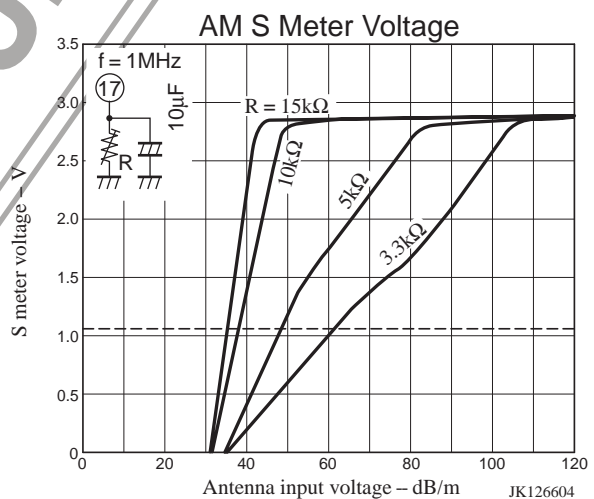
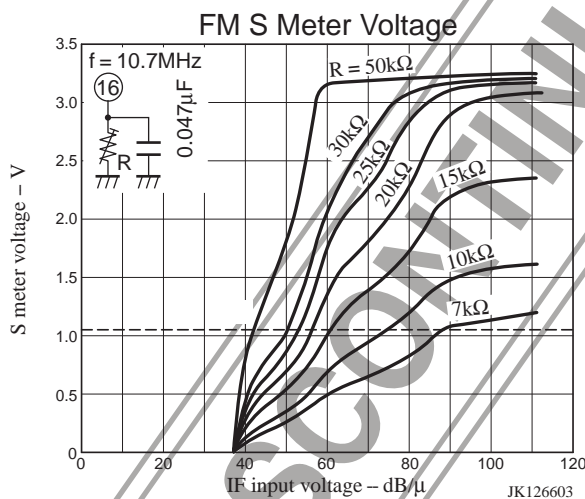
1. LED driver, muting drive output, stop signal (SD).

- For LED drive, muting drive output, stop signal, the output at pin 8 is used.
- Voltage on pin 8, when tuned, turns from "H" to "L" . (Active-low)
- Signal bandwidth at pin 8
 - For AM, the bandwidth depends on the C.F (BFU450CN) at pin 14. If a capacitor is connected in place of the C.F, the bandwidth will get wider.
 - For FM, the bandwidth depends on the resistance across pins 9 and 22. If the resistance is increased, the bandwidth will get narrower. R = 15k Ω makes the bandwidth approximately 110kHz.



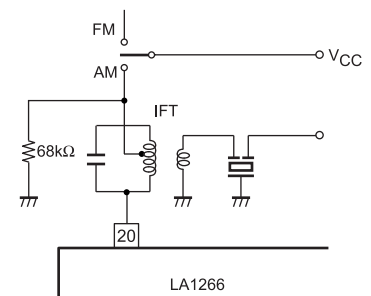
• Sensitivity adjustment of LED, muting, stop signal

- For FM, the semifixed variable resistor across pin 16 and GND is used.
 - For AM, the semifixed variable resistor across pin 17 and GND is used.
- The relation (for AM, FM) between signal meter voltage and input voltage with the resistance of the semifixed variable resistor as a parameter is shown below.



2. AM/FM changeover

- AM/FM changeover is made using pin 20 as shown right.
- However, the voltage on pin 20 relative to V_{CC} (pin 7) must be within the range of +0.1V to -0.8V. If not within this range, distortion and selectivity will get worse. A resistance of 68k Ω at the IFT cold terminal, which is used to prevent the changeover circuit from malfunctioning, must be connected.



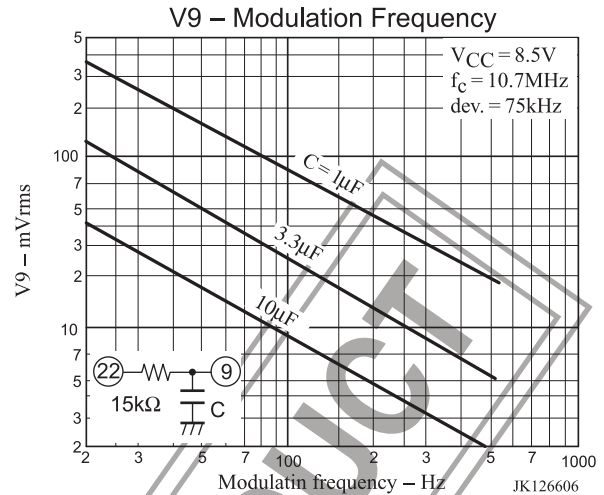
3. Local OSC buffer output

- When local OSC buffer output waveform is saw-toothed at the SW mode, connect a resistance of 1.2k Ω or thereabouts across pin 24 and GND.

4. Capacitance across pin 9 and GND

A large capacitance across pin 9 and GND may cause a misstop at an adjacent channel when the channel select speed is made faster at the automatic channel select mode. In this case, decrease the capacitance across pin 9 and GND.

However, if too decreased, the LED will flutter at low modulation frequencies at the time of detuning. Therefore, it is recommended to fix the capacitance across pin 9 and GND to be 3.3 μ F to 10 μ F. The relation between modulation frequency and demodulation output voltage on pin 9 with the capacitance across pin 9 and GND as a parameter is shown right.



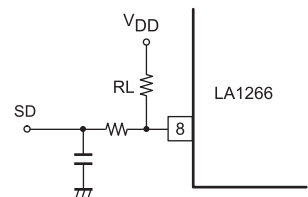
- If the coupling coefficient of the local OSC coil is small and an antiresonance point of approximately 100MHz is present or the stray capacitance across pin 24 and pin 23 is large, a parasitic oscillation of approximately 100MHz may occur in the buffer output (pin 24). In this case, connect a capacitance of approximately 30pF across pin 24 and GND.

6. AM OSC coil

Generally speaking, the following should be noted. Avoid winding with loose coupling between primary side and secondary side (especially SW1, SW2). To be concrete, the pot core type is better than the screw type which is loose in coupling. This prevents the local OSC frequency from turning third resonance frequency related to the coupling coefficient.

7. Resistance across pin 8 and V_{DD}

If pin 8 is used for stop signal (SD) only, without using LED, it is recommended to fix resistance R_L across pin 8 and V_{DD} to be 51k Ω to 100k Ω .

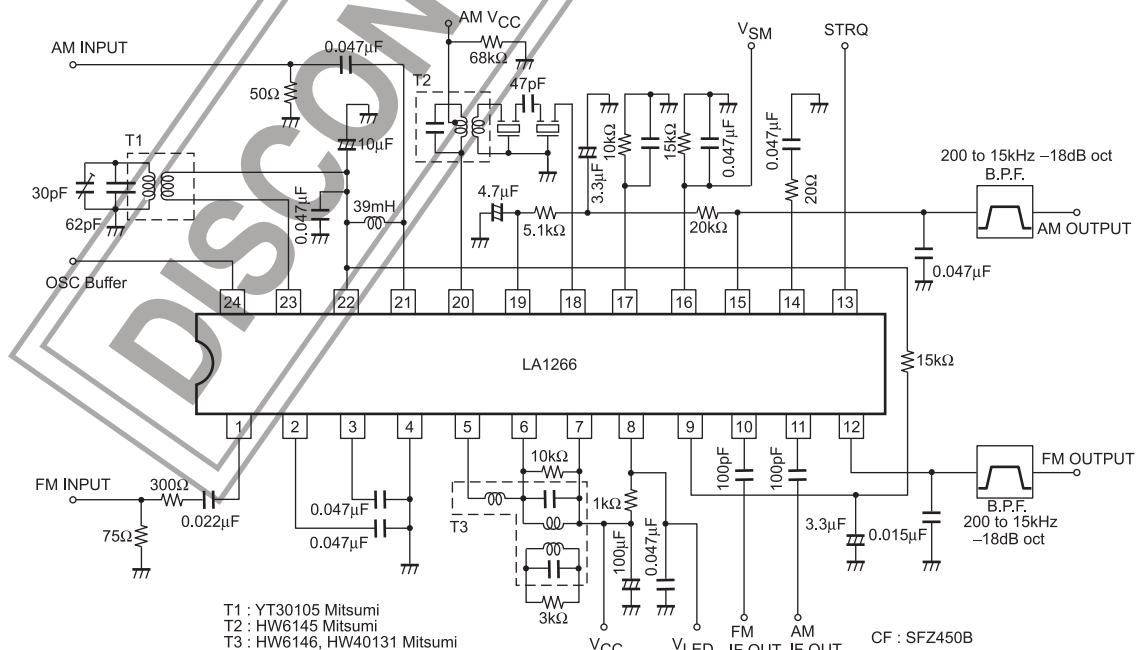


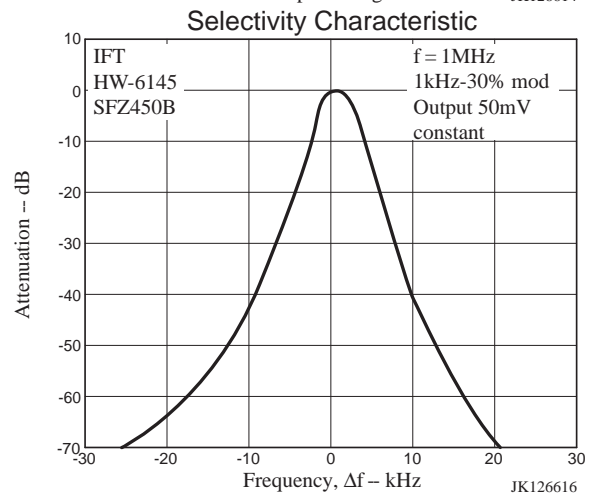
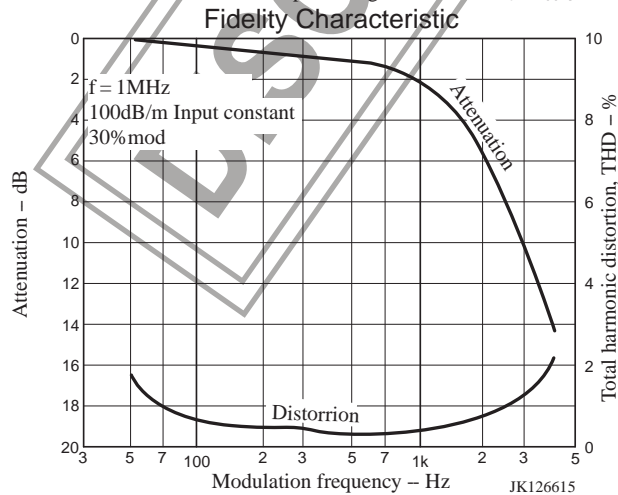
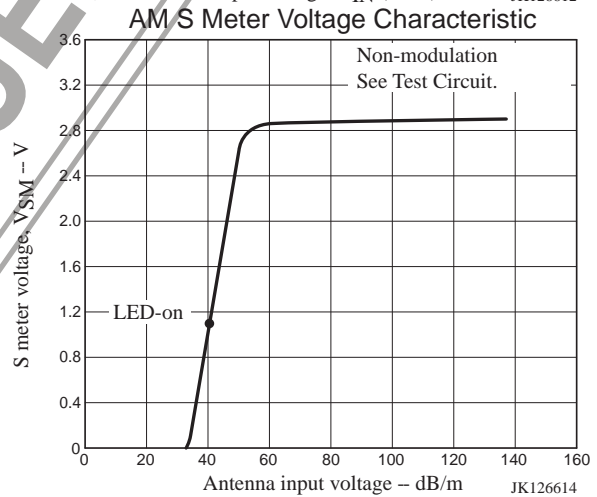
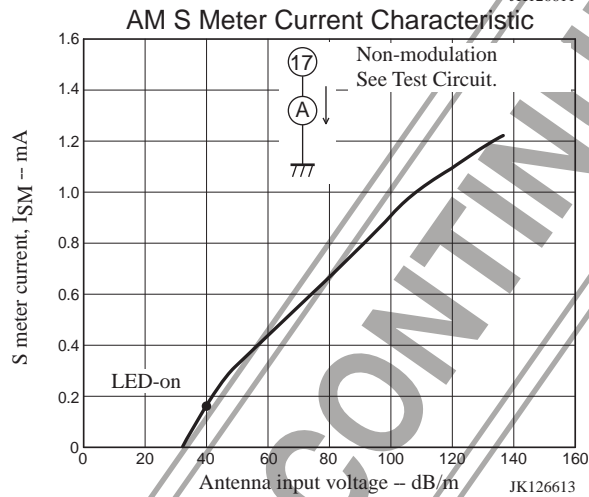
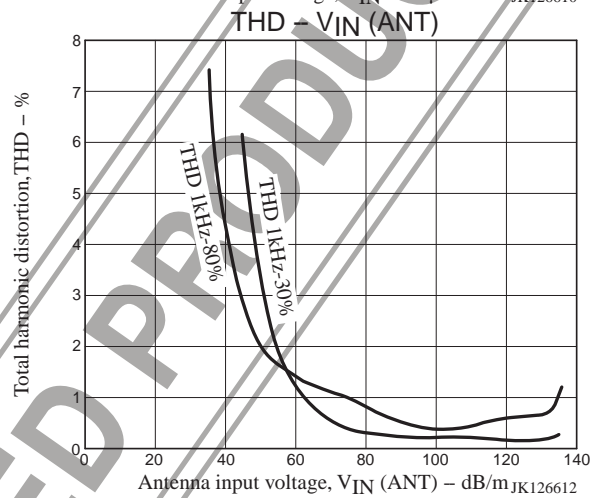
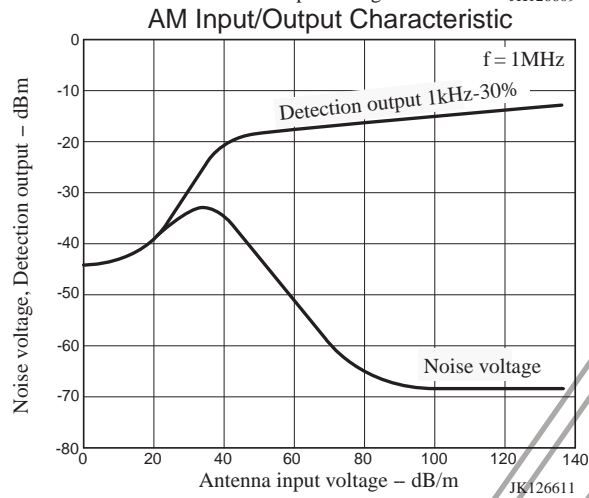
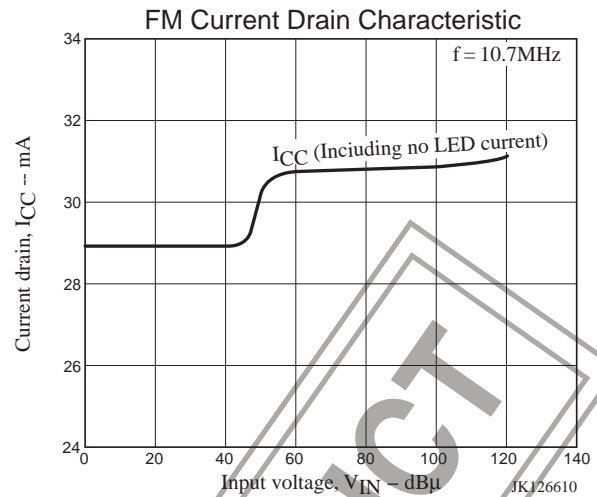
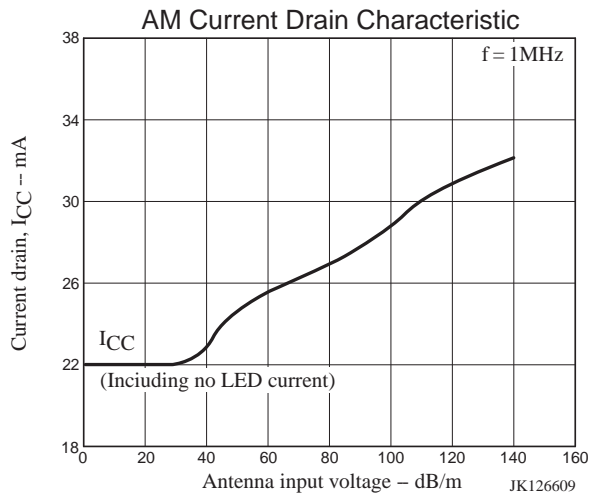
- To prevent whistle from worsening, make the pattern of AM output pin 15 as short as possible.

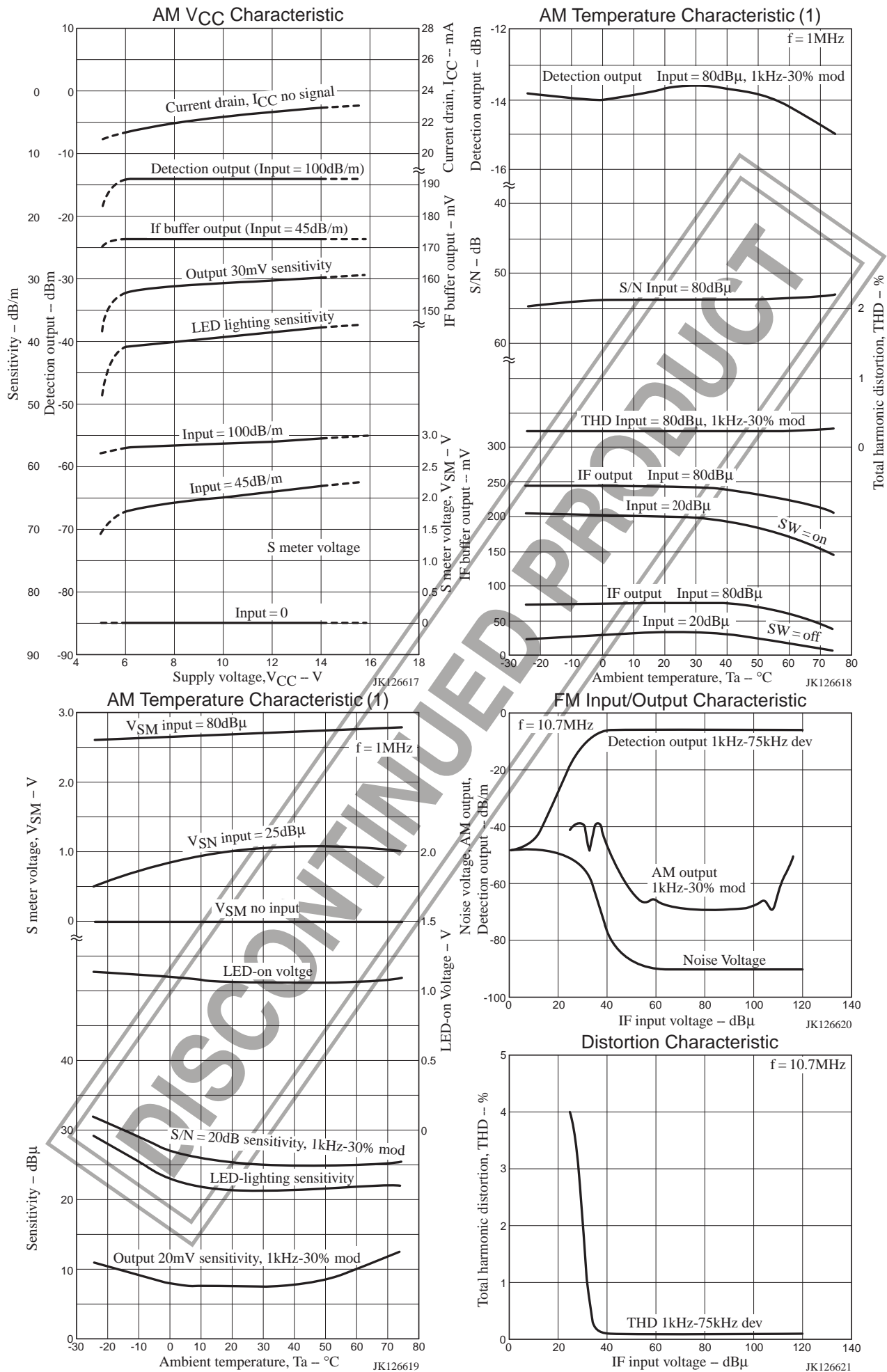
9. AM, FM IF buffer output

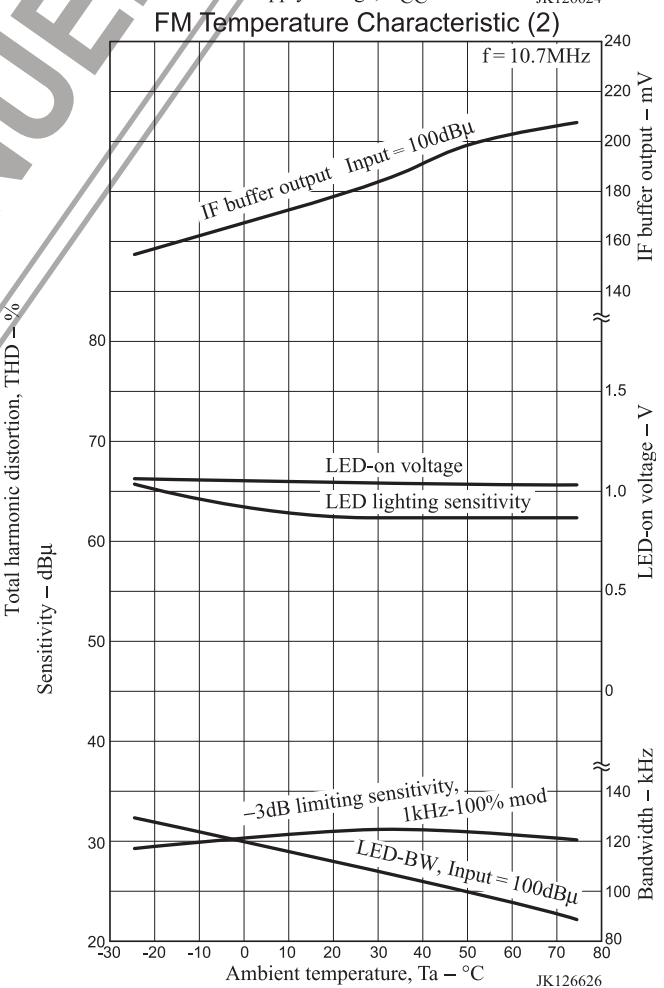
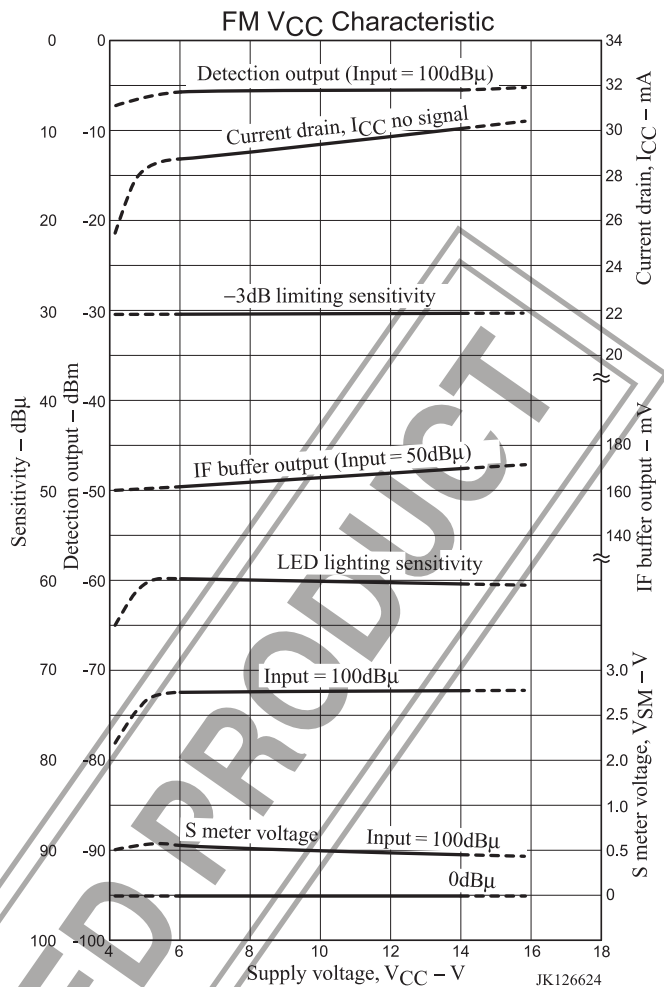
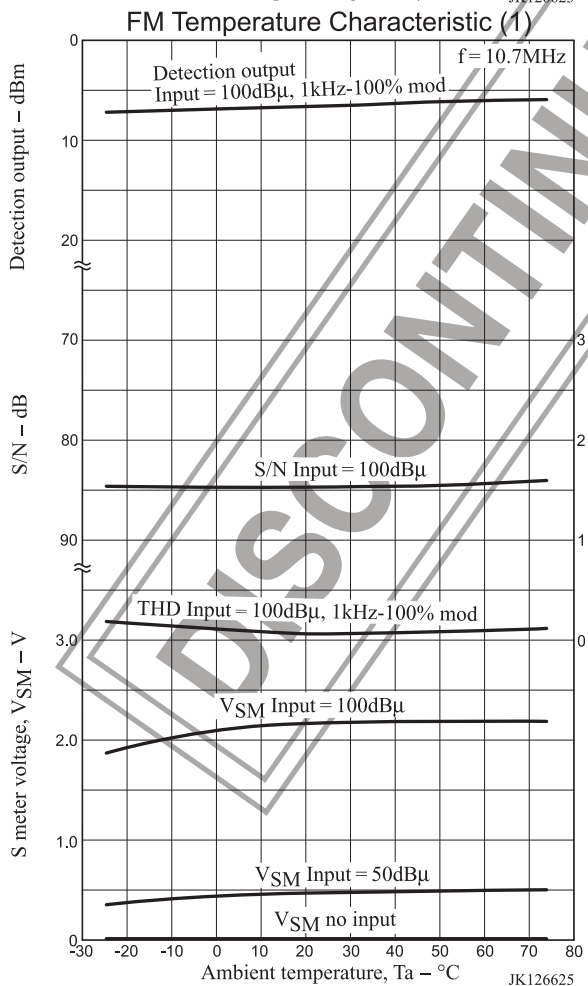
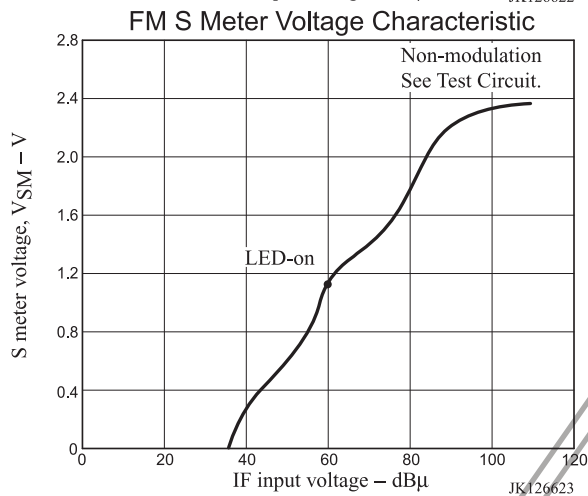
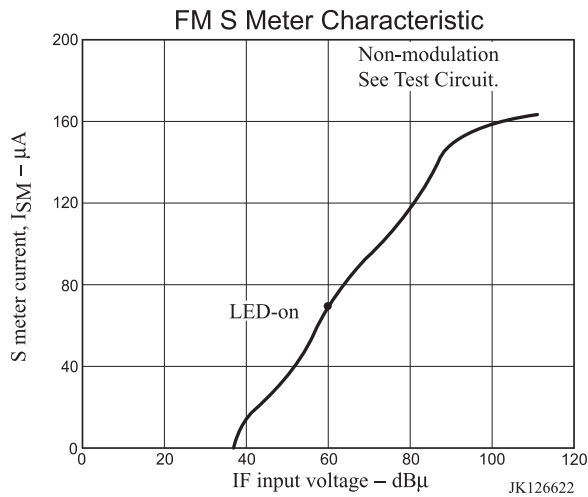
Application of a voltage to pin 13 (STRQ) causes AM IF(455kHz) signal (at AM mode) and FM IF(10.7MHz) signal (at FM mode) to be delivered at pin 11 and pin 10, respectively. It is recommended that the voltage to be applied to

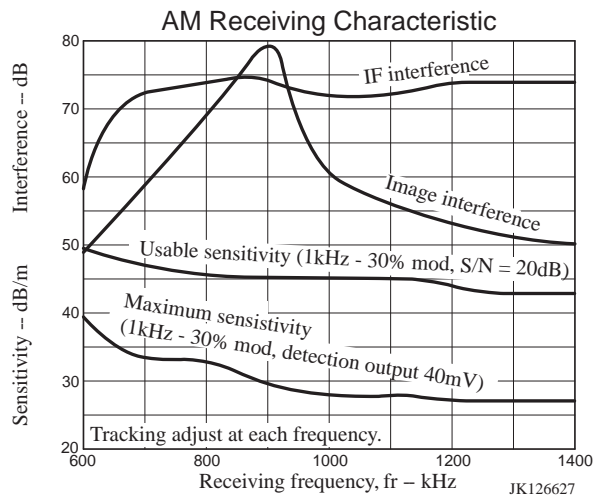
Test Circuit : FM, AM-MW









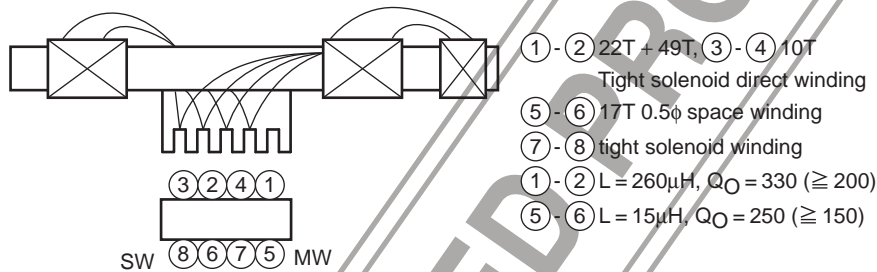


Coil Specifications

MW antenna

Bar antenna (for PVC22KTL)

- TN-10896 (Mitsumi)

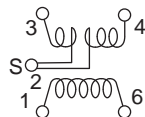


Loop antenna (for SVC321)

- LA300 (Korin Giken)

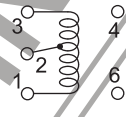
Loop antenna. matching coil

- KL-412



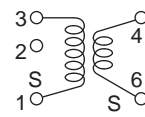
- ① - ⑥ 15.5T, ③ - ② 7T,
② - ④ 58T
 $Q_0 = 200 \pm 20\%$
 $L = 248\mu\text{H} \pm 10\%$

- YT-30150 (Mitsumi)



- ③ - ② 32T, ② - ① 32T,
0.07mm2VEW
 $Q_0 = 140$, $L = 140\mu\text{H}$

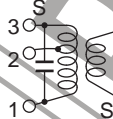
- KO-387 (Korin Giken)
For SVC321



- ① - ③ 48T, ④ - ⑥ 20T
 $Q_0 = 150 \pm 20\%$

AM IFT coil

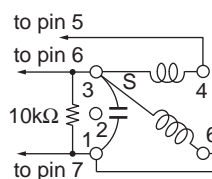
Matching coil for SFZ450B
(2-element type)



- HW-6145 (Mitsumi)
- ③ - ② 67T, ⑥ - ④ 10T
② - ① 85T
 $Q_0 = 70 \pm 20\%$, $f = 450\text{kHz}$
Internal 180pF

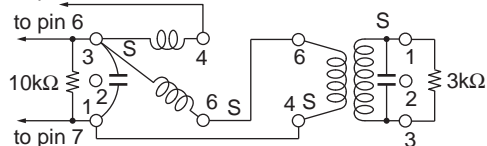
FM double tuning detection

HW-6146



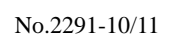
- HW-6146 (Mitsumi)
- ③ - ④ 86.5T
③ - ⑥ 13.5T
 $Q_0 = 50 \pm 20\%$
Internal 100pF $\pm 10\%$

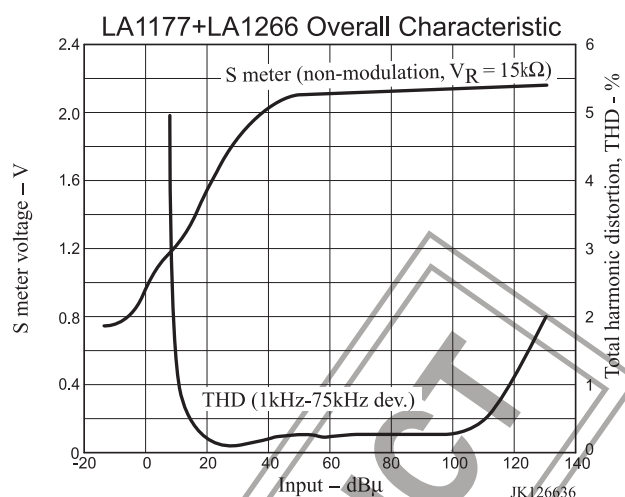
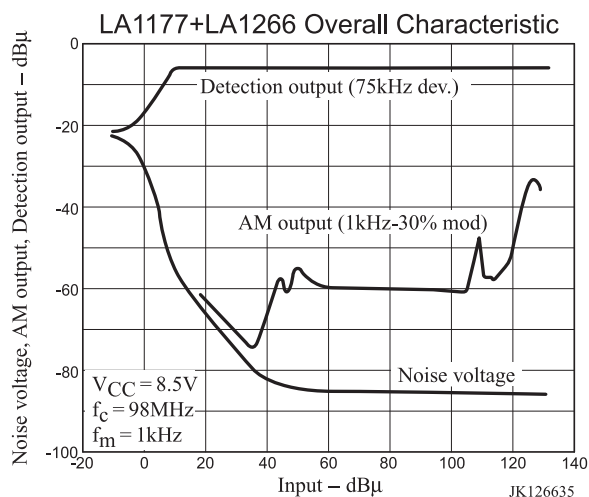
HW-40131



- HW-40131 (Mitsumi)
- ④ - ⑥ 1T
① - ③ 19T
 $Q_0 = 35 \pm 20\%$
Internal 100pF $\pm 10\%$

Sample Application Circuit : LA1177, LA1266, LM7000





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